NSN 5961-01-359-2002

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View Online at https://aerobasegroup.com/nsn/5961-01-359-2002 **Inclosure Material:** Plastic or ceramic **Overall Length:** Between 0.260 inches and 0.280 inches **Terminal Length:** 0.500 inches **Overall Height:** Between 0.125 inches and 0.165 inches **Overall Width:** Between 0.160 inches and 0.215 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-237 **Mounting Method: Terminal Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 drain to source voltage and 60.0 drain to gate voltage and 15.0 gate to source voltage **Current Rating Per Characteristic:** 0.50 milliamperes on-state drain current and 10.00 milliamperes peak pulse current **Power Rating Per Characteristic:** 1.0 watts off-state power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No